MAX3491ExxD Rev. A

RELIABILITY REPORT

FOR

MAX3491ExxD

PLASTIC ENCAPSULATED DEVICES

April 15, 2003

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

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Conclusion

The MAX3491E successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX3491E is a ±15kV ESD-protected, +3.3V, low-power transceivers for RS-485 and RS-422 communications. The device contains one driver and one receiver. The MAX3491E transmits up to 12Mbps.

The device features enhanced electrostatic discharge (ESD) protection. All transmitter outputs and receiver inputs are protected to ± 15 kV using IEC 1000-4-2 Air-Gap Discharge, ± 8 kV using IEC 1000-4-2 Contact Discharge, and ± 15 kV using the Human Body Model.

Drivers are short-circuit current limited and are protected against excessive power dissipation by thermal shutdown circuitry that places the driver outputs into a high-impedance state. The receiver input has a fail-safe feature that guarantees a logic-high output if both inputs are open circuit.

The MAX3491E feature full duplex communication.

B. Absolute Maximum Ratings

<u>ltem</u>	Rating		
Supply Voltage (V _{CC})	7V		
Control Input Voltage (/RE, DE)	-0.3V to 7V		
Driver Input Voltage (DI)	-0.3V to 7V		
Driver Output Voltage (A, B, Y, Z)	-7.5V to 12.5V		
Receiver Input Voltage (A, B)	-7.5V to 12.5V		
Receiver Output Voltage (RO)	-0.3V to (V _{CC} + 0.3V)		
Storage Temp.	-65°C to +160°C		
Lead Temp. (10 sec.)	+300°C		
Power Dissipation	471mW		
Derates above +70°C	5.88mW/°C		
Continuous Power Dissipation (+70°C)			
14-Pin DIP	800mW		
14-Pin NSO	677mW		
Derates above +70°C			
14-Pin DIP	10.0mW/°C		
14-Pin NSO	8.33mW/°C		

II. Manufacturing Information

A. Description/Function:	3.3V-Powered, +/-15KV ESD-Protected 12Mbps True RS-485/RS-422 Transceiver
B. Process:	S3 (Standard 3 micron silicon gate CMOS)
C. Number of Device Transisto	ors: 761
D. Fabrication Location:	Oregon, USA
E. Assembly Location:	Philippines, Malaysia or Thailand
F. Date of Initial Production:	April, 1999

III. Packaging Information

A. Package Type:	14 Lead PDIP	14 Lead NSO
B. Lead Frame:	Copper	Copper
C. Lead Finish:	Solder Plate	Solder Plate
D. Die Attach:	Silver-filled Epoxy	Silver-filled Epoxy
E. Bondwire:	Gold (1.3 mil dia.)	Gold (1.3 mil dia.)
F. Mold Material:	Epoxy with silica filler	Epoxy with silica filler
G. Assembly Diagram:	Buildsheet # 05-1901-0086	Buildsheet #05-1901-0087
H. Flammability Rating:	Class UL94-V0	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard JESD22-A112:	Level 1	Level 1

IV. Die Information

A. Dimensions:	86 x 146 mils
B. Passivation:	Si_3N_4/SiO_2 (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Aluminum/Si (Si = 1%)
D. Backside Metallization:	None
E. Minimum Metal Width:	3 microns (as drawn)
F. Minimum Metal Spacing:	3 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

Α.	Quality Assurance Contacts:	Jim Pedicord	(Reliability Lab Manager)
		Bryan Preeshl	(Executive Director of QA)
		Kenneth Huening	(Vice President)

- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4389 \times 960 \times 2}$ (Chi square value for MTTF upper limit) Temperature Acceleration factor assuming an activation energy of 0.8eV $\lambda = 1.13 \times 10^{-9}$ $\lambda = 1.13 \text{ F.I.T.}$ (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on rejects from lots exceeding this level. The attached Burn-In Schematic (Spec. # 06-5082) shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors quarterly for each process. This data is published in the Product Reliability Report (**RR-1M**).

B. Moisture Resistance Tests

Maxim evaluates pressure pot stress from every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

C. E.S.D. and Latch-Up Testing

The RS17-1 die type has been found to have all pins able to withstand a transient pulse of ± 2500 V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of ± 250 mA.

Table 1 Reliability Evaluation Test Results

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test	t (Note 1)				
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		960	0
Moisture Testi	ng (Note 2)				
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality		77	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical Str	ress (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality		77	0

Note 1: Life Test Data may represent plastic DIP qualification lots. Note 2: Generic package/process data.

Attachment #1

	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V _{PS1} <u>3/</u>	All V _{PS1} pins
2.	All input and output pins	All other input-output pins

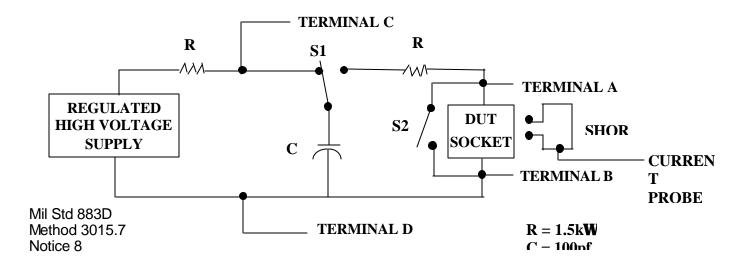
TABLE II. <u>F</u>	Pin combination to be tested.	<u>1/ 2/</u>
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- <u>1/</u> Table II is restated in narrative form in 3.4 below.
- $\overline{2/}$ No connects are not to be tested.
- $\overline{3}$ Repeat pin combination I for each named Power supply and for ground

(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_{S}$, $-V_{S}$, V_{REF} , etc).

3.4 Pin combinations to be tested.

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., V_{SS1} , or V_{SS2} or V_{SS3} or V_{CC1} , or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



PKG.CODE: P Cav./Pad SI	APPRON PKG, DESIGN	/ALS DATE	NIXIXI BUILDSHEET NUMBER: REV.: 05-1901-0086 A

